



INTERNATIONAL ATOMIC ENERGY AGENCY
UNITED NATIONS EDUCATIONAL, SCIENTIFIC AND CULTURAL ORGANIZATION



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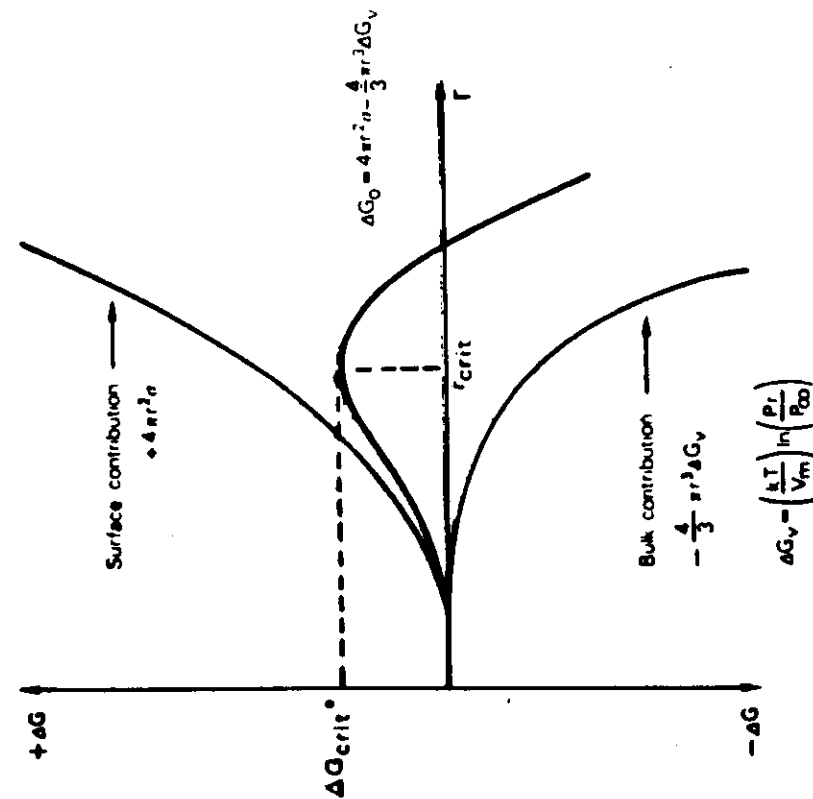
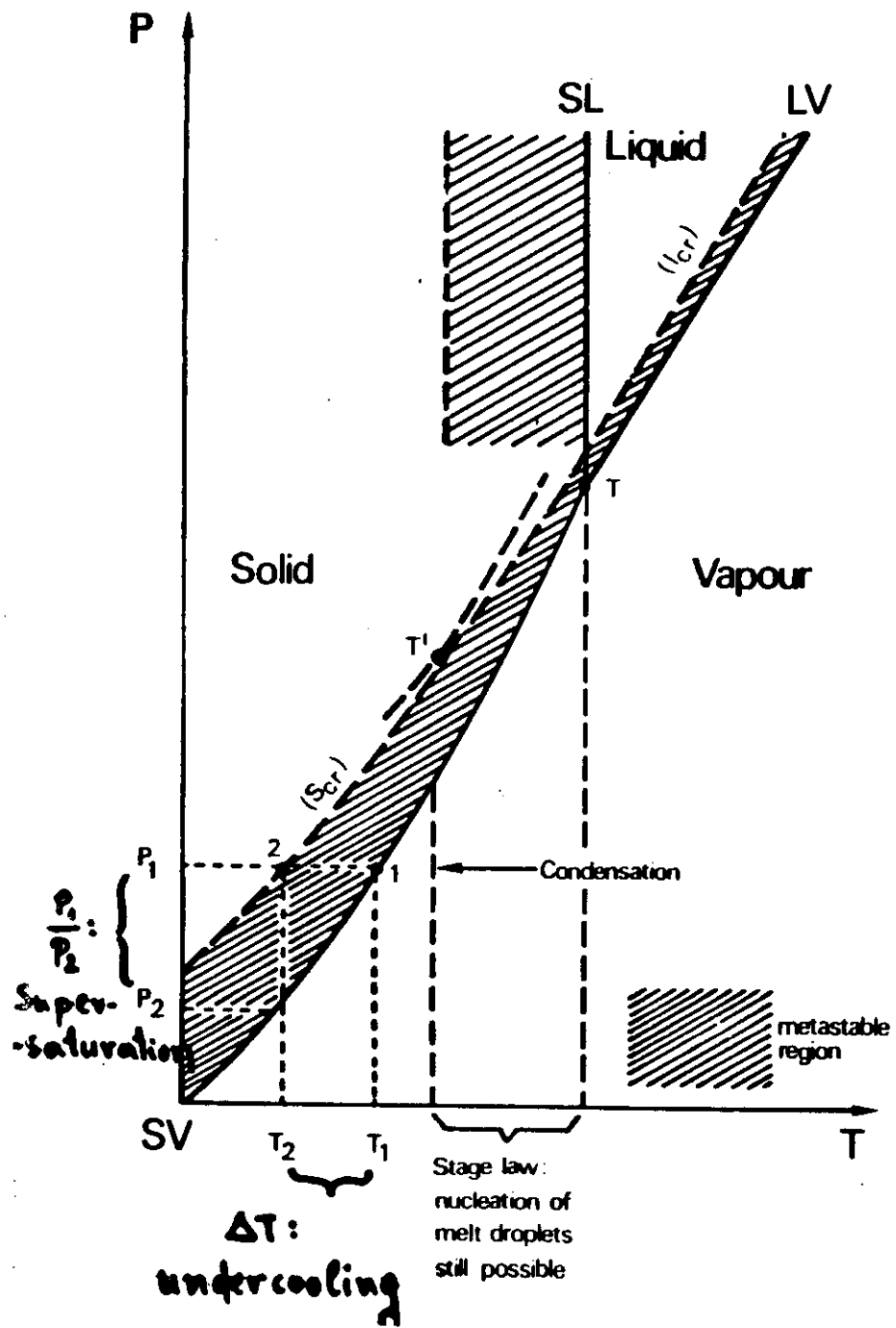
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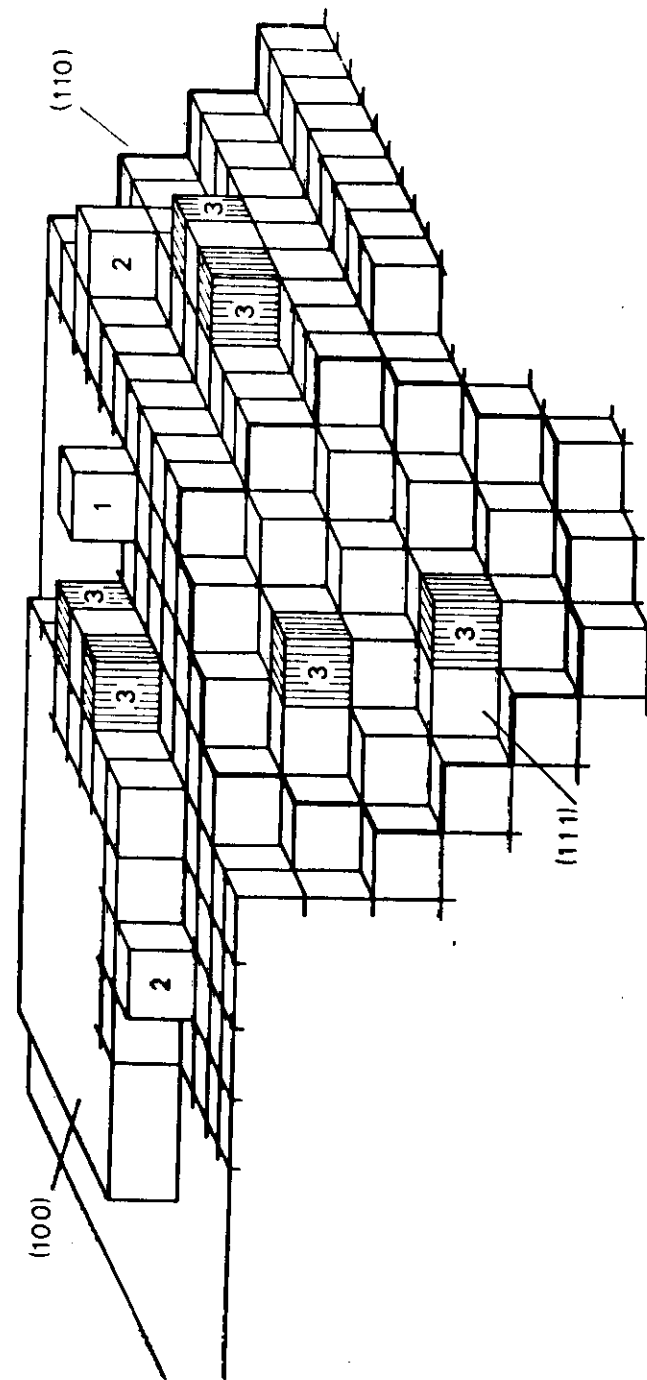
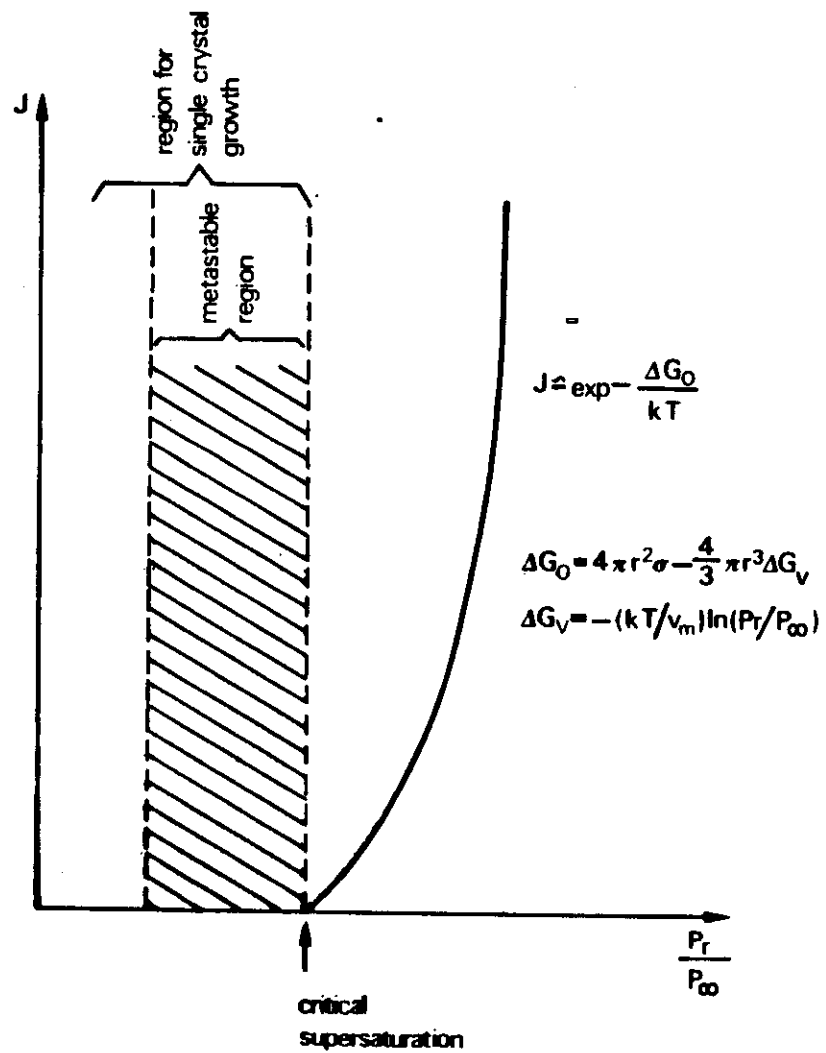
WORKSHOP ON SPACE PHYSICS:
"Materials in Microgravity"
27 February - 17 March 1989

"Crystal Growth: Fundamental"

E. KALDIS
ETH
Zurich, Switzerland

Please note: These are preliminary notes intended for internal distribution only.





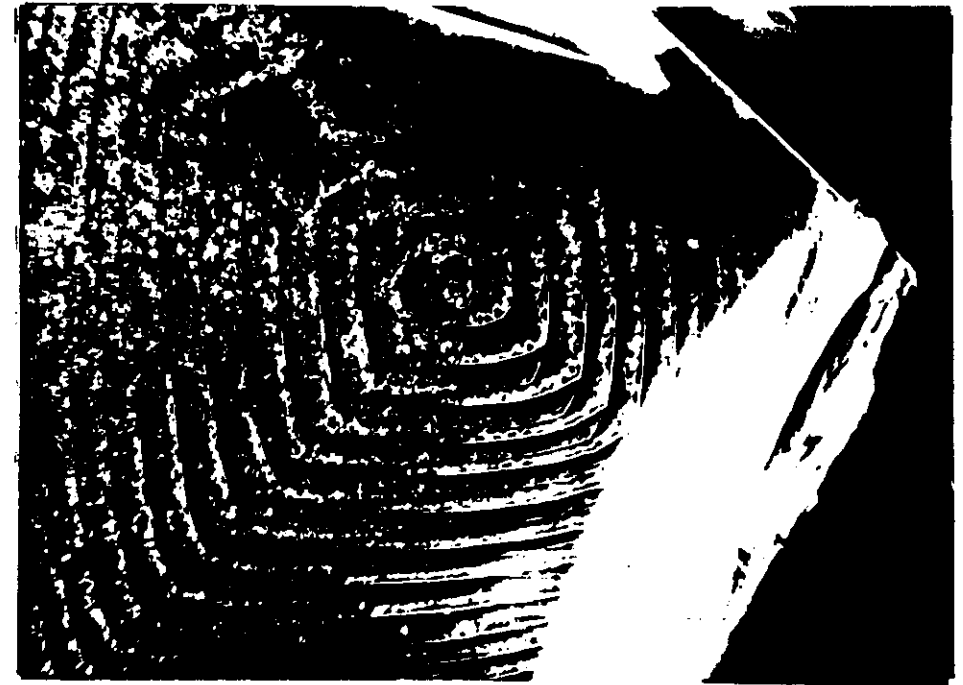
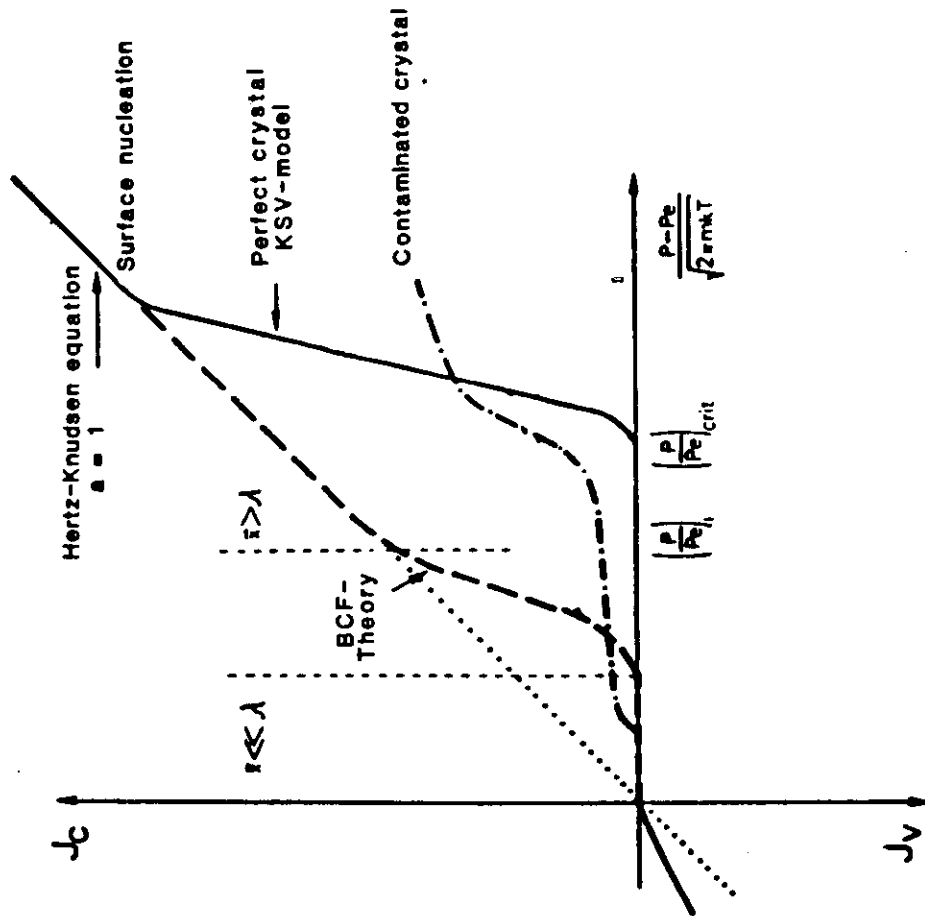
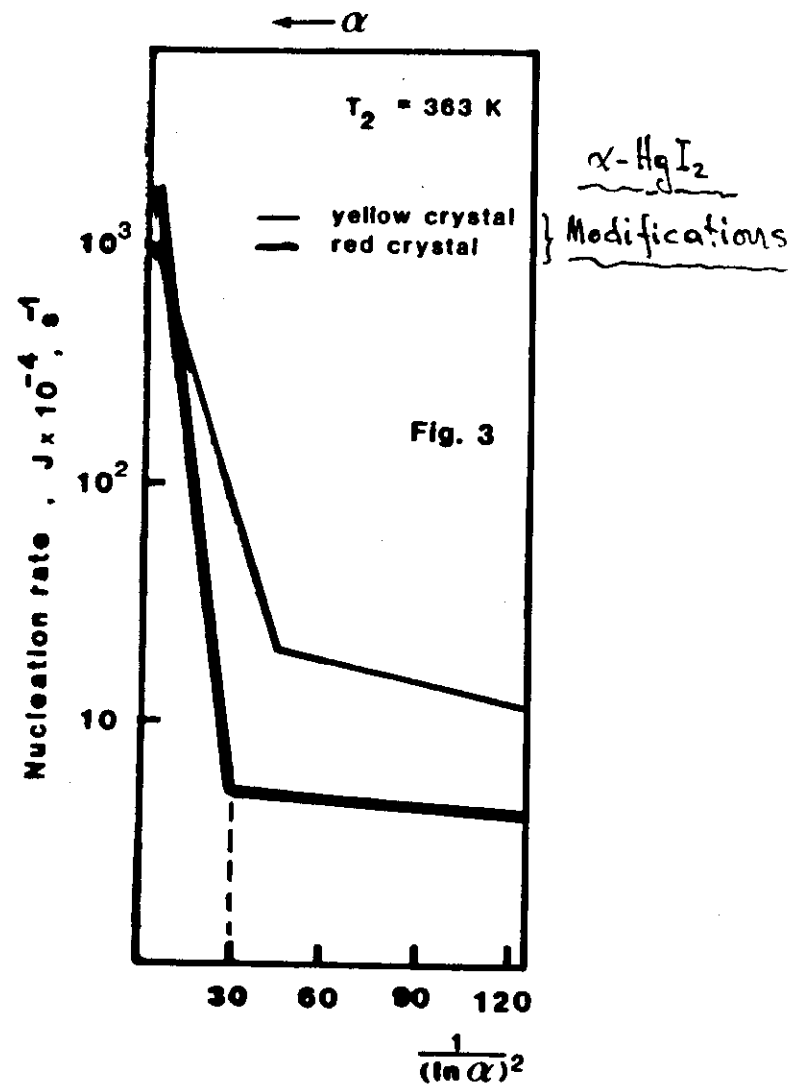
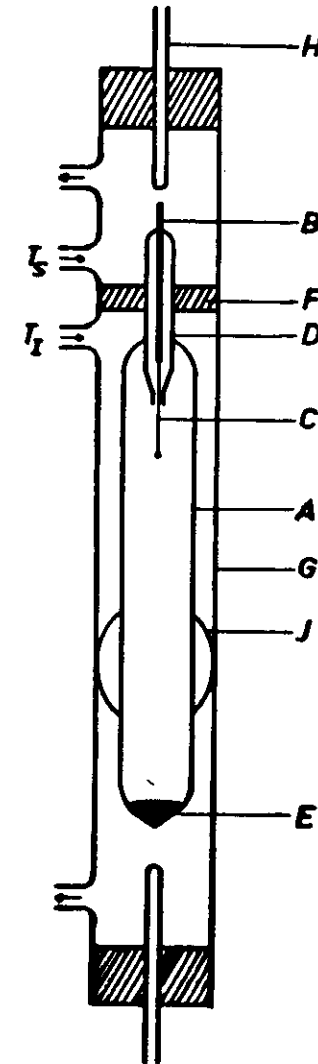


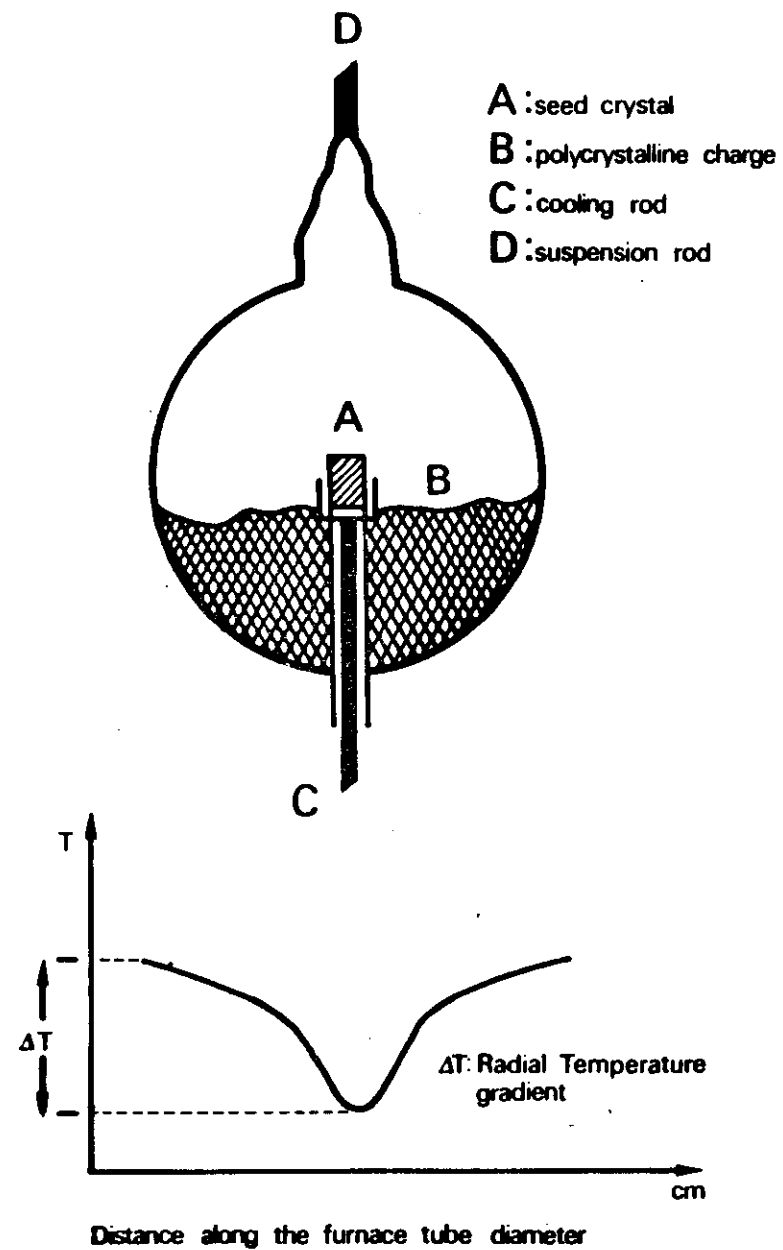
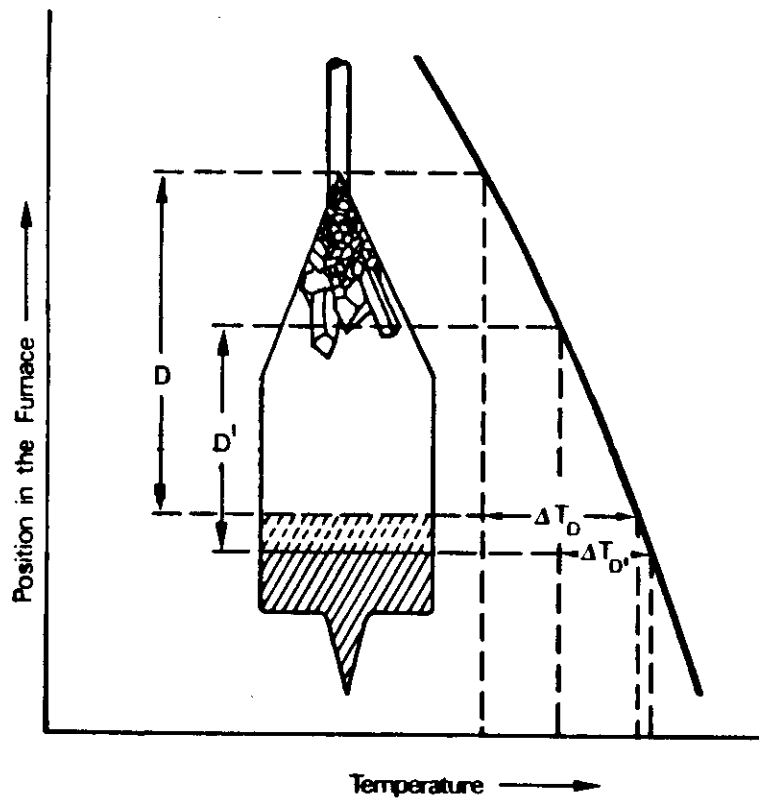
FIG. 3.9 a) An optical micrograph of an as-grown (001) facet showing the spiral pattern of an α -HgI₂ crystal in the presence of polyethylene dopant.



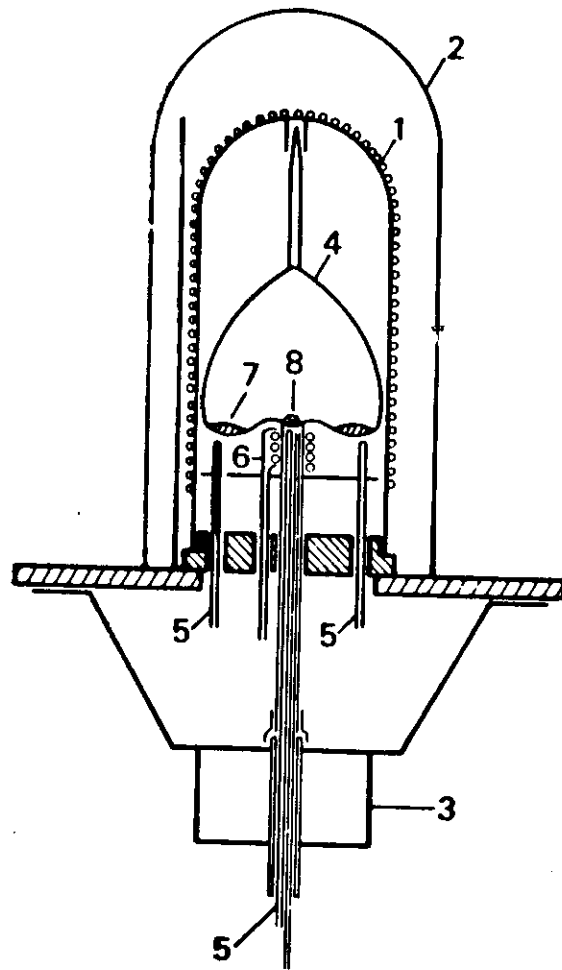
Nucleation control

- Reduction of the surface area of the substrate





Principles of the Vapour Growth of Single Crystals



Furnace and ampoule design (schematic) used in the temperature gradient reversal methods. (1) silica furnace. (2) thermal shield of Duran glass. (3) rotation mechanism. (4) ampoule for crystal growth. (5) thermocouples. (6) bottom heater. (7) charge. (8) crystal.

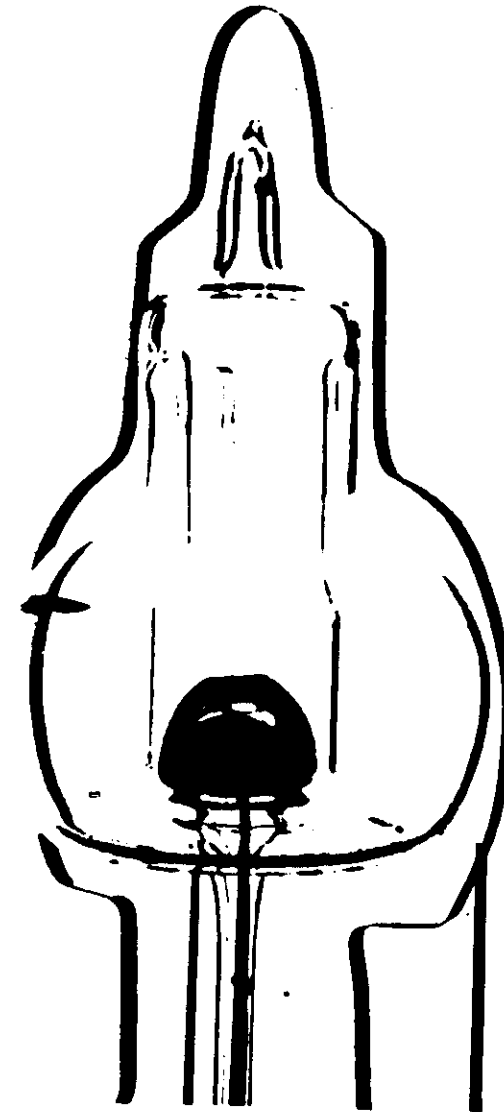




Fig.6.2 Growth striations revealed by chemical polishing with 20% solution in water. Slab was cut from a crystal grown in a vertical furnace using the TOM method. After SCHIEBER et al., 1976